Optical Conductivity from a Holographic Lattice

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Based on work with Gary Horowitz and Jorge Santos







Strongly Interacting Matter at Finite Temperature and Density



Boundary field theory d=2+1

- Bulk d=3+1 black hole
- Hawking radiation = finite temperature
- Electrically charged (Reissner-Nordstrom) = finite density

Optical Conductivity

 $j(\omega) = \sigma(\omega)E(\omega)$



Herzog, Kovtun, Sachdev and Son; Hartnoll

Optical Conductivity

 $j(\omega) = \sigma(\omega)E(\omega)$



Herzog, Kovtun, Sachdev and Son; Hartnoll

Resolving the Delta-Function

 $\operatorname{Re} \sigma(\omega) \sim K \,\delta(\omega)$

Due to: • Finite density of charge carriers

• Translational invariance

Goal: Break translational invariance

Building the Lattice

$$\mathcal{L} = \mathcal{L}_{\rm CFT} + \mu \mathcal{Q} + \phi_0(x, y)\mathcal{O}$$

Introduce a neutral, bulk scalar field: $\Phi \leftrightarrow \mathcal{O}$ Pick $m_{\Phi}^2 L^2 = -1 \implies$ relevant operator:

$$\Phi \rightarrow z\phi_0 + z^2\phi_1 + \dots$$
Source: $\phi_0 = A\cos(k_L x)$

The Lattice

Solve Einstein equations subject to lattice boundary conditions: $A_0(z,x)$, $\Phi(x,z)$ and

$$ds^{2} = \frac{L^{2}}{z^{2}} \Big[-g_{tt}(z,x)dt^{2} + g_{zz}(z,x)dz^{2} + g_{xx}(z,x)(dx + a(z,x)dz)^{2} + g_{yy}(z,x)dy^{2} \Big]$$



parameters T, μ, k_L, A

Charge Density



Charge Density $\sim k_L^2$

Band Structure

Add a probe scalar field in the lattice background



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Band gaps negligible

Perturbing the Lattice

 $\delta g_{tt}, \ \delta g_{tz}, \ \delta g_{tx}, \ \delta g_{zz}, \ \delta g_{zx}, \ \delta g_{xx}, \ \delta g_{yy}$

 $\delta A_t, \ \delta A_z, \ \delta A_x, \ \delta \Phi$

Optical Conductivity

 $j(\omega) = \sigma(\omega)E(\omega)$



 $\mu = 1.4$ $T = 0.115\mu$ $k_L = 2$ A = 1.5

Low Frequency Behaviour



$$\sigma(\omega) = \frac{K\tau}{1 - i\omega\tau}$$

Note: No quasiparticles

$$\omega \leq T$$

DC Resistivity



Nearly all temperature dependence in au

DC Resistivity

Low energy excitations around black hole governed by *locally critical* theory

- Field Theory: $z \to \infty$
- Geometry: $AdS_2 \times \mathbf{R}^2$

Hartnoll and Hofman:

$$\rho \sim T^{2\nu - 1}$$

$$\nu = \frac{1}{2}\sqrt{5 + 2(k/\mu)^2 - 4\sqrt{1 + (k/\mu)^2}}$$

DC Resistivity



Mid-Frequency Behaviour $\omega \gtrsim T$
 $2 < \omega \tau < 8$



$$|\sigma(\omega)| = \frac{B}{\omega^{2/3}} + C$$

Not arising from near horizon geometry alone

Robust Power-Law

Log-log plots



 $\eta \&1.0 = T$, $\eta \&11.0 = T$, $\eta &80.0 = T$

$$k_L = 3, \ k_L = 1, \ k_L = 2$$

Note: No offset, C



van der Marel et al.



 $Bi_2Sr_2Ca_{0.92}Y_{0.08}Cu_2O_{8+\delta}$

Summary

Why?